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Magnetic-field-induced stabilization of nonequilibrium superconductivity in a normal-metal/insulator/superconductor junction

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A small magnetic field is found to enhance relaxation processes in a superconductor, thus stabilizing superconductivity in nonequilibrium conditions. In a normal-metal (N)/insulator/superconductor (S) tunnel junction, applying a field of the order of 100 μ T leads to significantly improved cooling of the N island by quasiparticle (QP) tunneling. These findings are attributed to faster QP relaxation within the S electrodes as a result of enhanced QP drain through regions with a locally suppressed energy gap due to magnetic vortices in the S leads at some distance from the junction.

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Introduction. In this Rapid Communication, we report an observation that appears counterintuitive at first: A small magnetic field is found to stabilize superconductivity under quasiparticle (QP) injection. In our experiment, the cooling power of normal-metal (N)/insulator (I)/superconductor (S) tunnel structures is enhanced in perpendicular magnetic fields $B_{\perp} \simeq 100 \ \mu T = 1$ G. A measured maximum temperature drop δT relative to a starting bath temperature $T_0 =$ 285 mK exhibiting this behavior is shown in Fig. 1(a). The improvement is unexpected, as in general the effect of a magnetic field is to suppress superconductivity. Electronic cooling in NIS junctions in the presence of magnetic fields in both perpendicular and parallel orientations has been studied before,¹ but only in higher fields where the cooling power was already reduced due to a diminishing superconducting energy gap Δ . On the other hand, the creation of magnetic vortices² has been shown to enhance QP relaxation in superconducting aluminum, as the QPs become trapped and thermalize in the regions of a reduced energy gap.³ Here we demonstrate that the additional relaxation channel due to an enhanced QP drain through regions occupied by magnetic vortices enhances the superconducting performance of S leads and improves the electronic cooling in NIS junctions. This can be of relevance in superconducting qubits,^{4–7} resonators,⁸ and in hybrid SINIS turnstiles⁹ in reducing the effects from nonequilibrium and residual QPs arising due to drive and microwave radiation from the environment. Moreover, improved relaxation caused by vortex creation in the S leads can partially explain the "reentrant superconductivity" observed in Zn and Al nanowires.^{10,11} In the present case, as sketched in Fig. 1(a), vortex formation in the S electrodes away from the NIS junction improves relaxation of the injected QPs and leads to enhanced cooling of the N island. In higher fields, vortices move closer to the junction, deteriorating the cooling power.

In a NIS junction, Δ acts as an energy filter for the tunneling QP.^{12–15} At low temperatures $k_{\rm B}T \ll \Delta$ and for bias voltages eV $\leq \Delta$ across the junction, the electrons in the N electrode cool considerably below the phonon temperature by hot QP extraction. The effect can be made to be more pronounced in a symmetric double-junction SINIS structure with a small N

island contacted to S leads via two NIS junctions,¹⁵ allowing to construct practical solid-state refrigerators for cooling thin-film detectors to temperatures close to 100 mK.^{16,17} The performance of actual devices depends crucially on the relaxation of the QPs that are injected into the S electrode, as the superconductor overheating diminishes the cooling power at a NIS junction because of enhanced QP backtunneling. The excess QP density close to the junction can be diminished by



FIG. 1. (Color online) (a) Maximum temperature drop δT in an optimally biased SINIS cooler in a perpendicular magnetic field B_{\perp} , at a bath temperature $T_0 = 285$ mK. The sketches show the S electrode geometry and qualitative vortex configurations at $B_{\perp} \leq 2$ G and at a value of B_{\perp} beyond the optimum point. The area inside the green (dashed) rectangle corresponds to that in the micrograph below. (b) Scanning electron micrograph of a typical structure, together with the measurement scheme (see the text for details). A Cu island (red, marked with N) in the middle is contacted to four superconducting Al electrodes (blue/dark) via Al oxide tunnel barriers for thermometry and temperature control. Replicas of each structure are visible due to the fabrication involving two-angle shadow evaporation of the metals.

fabricating very thick S electrodes,¹⁶ or covering them partially by a layer of normal metal that acts as a QP trap.^{18–20} The QP population is typically modeled in terms of a diffusion equation, describing their recombination retarded by phonon retrapping, and other loss mechanisms.^{21–25} Converting the excess density into an effective, position-dependent temperature T(x), one finds^{26,27} that at phonon temperatures $k_{\rm B}T \ll \Delta$ the S leads can be overheated on a length scale ranging from tens of micrometers to a millimeter, as the electron-phonon relaxation and electronic heat conduction are exponentially suppressed compared to their normal-state values.^{22,28}

Experiment. Here we present data from one of several measured symmetric SINIS structures similar to that shown in Fig. 1(b), fabricated at different times, and electrically characterized in a dilution refrigerator down to 50 mK bath temperature. The same qualitative behavior was observed in all structures with the same geometry. A copper island of area $A_N \simeq 2.7 \times 0.7 \ \mu m^2$ is contacted by four overlap-type Al/Al-oxide/Cu NIS junctions. The Al electrodes with a zero-temperature energy gap $\Delta_0 \simeq 210 \ \mu eV$ become superconducting below $T_{\rm C} \simeq 1.4$ K. Compared to the two small (probe) junctions in the middle, the two outer (cooler) junctions at the ends of the island have a larger overlap area and therefore lower normal-state tunnel resistance $R_{\rm T} \simeq 1.1 \text{ k}\Omega$ each. The structures were fabricated on an oxidized silicon substrate by standard electron beam lithography and two-angle shadow evaporation of Al and Cu through a polymer resist mask. First, an Al layer of thickness $d_{\rm S} \simeq 30$ nm was deposited, followed by in situ oxidation in the e-beam evaporator chamber in a few millibars of pure oxygen for a few minutes. Finally, a Cu layer of thickness $d_{\rm N} \simeq 30$ nm was evaporated at a different angle, forming the N island with four tunnel contacts to the Al electrodes. In addition, Cu replicas of the Al leads form large-area tunnel junctions by partly covering the Al layer, serving as QP traps, albeit of suboptimal performance.¹⁹

The island electron temperature T_N is measured by biasing the probe junctions by a constant current I_{th} , and measuring the voltage drop V_{th} , calibrated against T_0 at V = 0. The solid lines in Fig. 2(a) show the measured T_N as a function of V at bath temperatures T_0 between 0.1 and 0.5 K, in zero field (red/light) and at $B_{\perp} \simeq 3$ G (blue/dark). In the following, the minimum T_N along each curve at a fixed T_0 is denoted by $T_{N,min}$, and the corresponding bias voltage by V_{opt} . The strong influence of small B_{\perp} on the cooling is evident: At eV $\simeq 2\Delta$ the maximum cooling $\delta T = T_{N,min} - T_{N,0}$ at each T_0 increases by several tens of percents. The cooler QP current displays analogous behavior [Fig. 2(b)]. At the same time the optimum bias voltage V_{opt} increases [Fig. 2(d)] while heating at $V > V_{opt}$ diminishes. The cooling enhancement is symmetric in the applied field.

The improved refrigeration is summarized in Fig. 2(c), where the symbols show the T_0 -dependent relative minimum temperature in zero field and close to optimum B_{\perp} . We observed the improved cooling also with Ag as the normal metal, in single NIS junctions with various gradually widening lead geometries close to the junction, and in a parallel field. In the latter case, the required fields were larger by an order of magnitude and dependent on the field orientation in the sample plane.

The thin-film Al leads behave as a type-II superconductor, so that B_{\perp} penetrates in the form of vortices.^{29,30} Based

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FIG. 2. (Color online) (a) Temperature $T_{\rm N}$ of the N island and (b) cooler SINIS *I-V* characteristic at several bath temperatures T_0 as functions of the cooler bias voltage V, in zero field (red/light) and at $B_{\perp} \simeq 3$ G (blue/dark). (c) Relative minimum temperature in zero field (red/light symbols) and at $B_{\perp} \simeq 3$ G (blue/dark symbols). The solid and dashed-dotted lines show the calculated temperature reduction for various degrees of thermalization of the QPs and of the island phonons (see text). (d) Optimum bias voltage $V_{\rm opt}$ vs B_{\perp} at $T_0 = 285$ mK, with the corresponding temperature drop in Fig. 1(a). (e) Phonon temperatures in zero (red/light, \bigtriangledown) and optimum (blue/dark, \triangle) field, required to reproduce the observed $T_{\rm N,min}$. The dashed line shows $T_{\rm ph} = T_0$.

on a typical normal-state resistivity $\rho = 3.5 \ \mu\Omega \, \text{cm}$ of our Al at 4.2 K,^{31,32} the elastic mean free path is $l \simeq 8$ nm. With the Bardeen-Cooper-Schrieffer (BCS) coherence length $\xi_0\simeq 1600$ nm and the London penetration depth $\lambda_L\simeq 16$ nm for bulk pure Al at low temperatures, one obtains $\xi =$ $0.855(\xi_0 l)^{1/2} \simeq 100 \text{ nm}$ and $\lambda = \lambda_L (\xi_0 / l)^{1/2} \simeq 230 \text{ nm}$ for our Al films with the Ginzburg-Landau parameter $\kappa = \lambda/\xi \simeq$ $2.4 > 1/\sqrt{2}$ and the lower critical field for the bulk material $H_{c1} \lesssim 100$ G. As sketched in Fig. 1(a), the S leads of the cooler junctions have an initial width of $\sim 1 \ \mu$ m. At a distance of 1 μ m away from the island, they widen to 2.5 μ m width and continue for 15 μ m before again widening to 10 μ m width and connecting to large-area bonding pads 350 μ m further away. The magnetic field below which vortices are completely expelled from a long and narrow S lead of width W is of the order of $B_0 = \Phi_0 / W^{2,33}$ where $\Phi_0 =$ $h/(2e) \simeq 2 \times 10^{-15}$ Wb is the magnetic flux quantum. For a strip of width $W = 10 \ \mu m$, we find $B_0 \simeq 0.2$ G, whereas $W = 2.5 \ \mu m$ results in $B_0 \simeq 3.3$ G. Taking into account the demagnetizing factor $1 - n_z \sim (0.5-2) \times 10^{-2}$ of our films we can conclude that the initial increase in $|\delta T|$ in Fig. 1(a) observed below 1 G and the turnback that starts close to 3 G are consistent with vortex penetration into the wide and narrow parts of the lead, respectively.

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In Ref. 3, with large-area NIS junctions, the increased subgap conductance at small B_{\perp} could be directly associated with the fraction of vortices in the junction area. In contrast, we do not observe an increase in the cooler junction subgap current in the small fields. The thermometer junctions with narrower S electrodes are not considerably affected in fields $B_{\perp} \lesssim 10$ G, even at bias voltages close to 2Δ , indicating that vortices exist only further away from these junctions.

Thermal model. To model the improved cooling, we assume quasiequilibrium with a local electronic temperature that is different from the bath temperature.¹⁴ The cooling power depends on the temperatures T_N and T_S of the N and S electrodes near the interface. They are found from the equation of heat balance in the N island

$$2\dot{Q}_{\rm N}(V, T_{\rm N}, T_{\rm S}) = \Sigma_{\rm N} \mathcal{V}_{\rm N} \left(T_{\rm ph}^5 - T_{\rm N}^5 \right) + P_0 \tag{1}$$

and of the heat conduction in each superconducting lead

$$\nabla \cdot [\kappa \nabla T(x)] = q(x), \tag{2}$$

with the boundary conditions $\mp \kappa AT'(0) = \dot{Q}_S$, and $T(x) \rightarrow T_0$ at $x \rightarrow \pm \infty$ for the right or left lead (*A* is a wire cross section). The temperature of the lead at the interface is $T_S \equiv T(x = 0)$. The first term on the right-hand side (rhs) of Eq. (1) describes the heat transferred to phonons in the normal island. The island volume and electron-phonon coupling constant are $\mathcal{V}_N = \mathcal{A}_N d_N$ and Σ_N , respectively. $P_0 \simeq 1$ fW in Eq. (1) is a constant residual power due to imperfect rf filtering of the measurement. The heat \dot{Q}_N extracted from the island through a single NIS junction and the heat \dot{Q}_S injected into a S lead by tunneling are

$$\dot{Q}_{\rm N,S} = \frac{1}{e^2 R_{\rm T}} \int n_{\rm S}(E_{\rm S}) E_{\rm N,S} [f_{T_{\rm N}}(E_{\rm N}) - f_{T_{\rm S}}(E_{\rm S})] dE.$$
(3)

Here, $E_{\rm N} = E - {\rm eV}/2$, $E_{\rm S} = E$, $f_{T_{\rm N},T_{\rm S}}(E) = 1/[\exp(E/k_{\rm B}T_{\rm N,S}) + 1]$ are the Fermi occupation factors, and $n_s(E) = (|E|/\sqrt{E^2 - \Delta^2})\theta(E^2 - \Delta^2)$ is the normalized BCS density of states (DOS).

The rhs of Eq. (2) is the power transferred from the unit volume of the superconductor into the (unbiased) normal trap with temperature T_0 . Similarly to Eq. (3),

$$q(x) = \frac{1}{e^2 \rho_{\text{tr}} d_{\text{S}}} \int n_{\text{S}}(E) E[f_T(E) - f_{T_0}(E)] dE$$
$$= [\mathcal{E}(T) - \mathcal{E}(T_0)] / \tau_{\text{tr}},$$

where $\tau_{tr}^{-1} = 1/(2e^2 N_0 \rho_{tr} d_S)$ is the time of relaxation to the trap, ρ_{tr} being the trap/superconductor tunnel resistance of unit contact area, and N_0 denotes the normal-state DOS at the Fermi energy per one spin projection, while $\mathcal{E}(T)$ is the internal energy density of the superconductor with the gap Δ at temperature T(x).³⁴ In Eq. (2) we assume that the electronic subsystem releases heat to the normal trap rather than directly to the phonon bath. Indeed, the trap relaxation rates are $\tau_{tr}^{-1} \sim 10^6 - 10^7 \text{ s}^{-1}$ for the contact resistances $\rho_{tr} \sim 3-0.3 \text{ k}\Omega(\mu\text{m})^2$ while the electron-phonon relaxation rate in aluminum is $\tau_{ph}^{-1} < 3 \times 10^5 \text{ s}^{-1}$ for the experimental temperatures. Equation (2) is obtained by averaging it over inhomogeneities in Δ , assumed to have a low areal density and a short scale compared to the inelastic relaxation length, i.e., the scale of T(x) variations. The

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thermal conductivity κ and the heat current into the trap q are spatially averaged quantities $\kappa = \kappa_{\rm S}(1-r) + \kappa_{\rm N}r$ and $q = q_{\rm S}(1-r) + q_{\rm N}r$ for a superconductor having a normal fraction r proportional to B_{\perp} , which models the presence of vortices. The thermal conductivity²⁸ $\kappa_{\rm S}$ and the heat current $q_{\rm S}$ of a superconductor at $k_{\rm B}T \ll \Delta$ are exponentially suppressed relative to their normal-state values $\kappa_{\rm N} = \mathcal{L}_0 \sigma_{\rm N} T$ and $q_{\rm N} = [(\pi^2 N_0 k_{\rm B}^2/3)(T^2 - T_0^2)]/\tau_{\rm tr}$ according to $\kappa_{\rm S}/\kappa_{\rm N} = (6/\pi^2)(\Delta/k_{\rm B}T)^2 e^{-\Delta/k_{\rm B}T}$ and $q_{\rm S} = (2\pi \Delta)^{3/2} N_0 k_{\rm B}^{1/2} [\sqrt{T} e^{-\Delta/k_{\rm B}T} - \sqrt{T_0} e^{-\Delta/k_{\rm B}T_0}]/(\pi \tau_{\rm tr})$. Here $\mathcal{L}_0 = (\pi^2/3)(k_{\rm B}/e)^2$, and $\sigma_{\rm N}$ is the Al normal-state electrical conductivity.

Because of exponentially small $\kappa_{\rm S}$ and $q_{\rm S}$ at $k_{\rm B}T \ll \Delta$, the temperature $T_{\rm S}$ can be very sensitive to the vortex fraction r. For reference, the black dotted line in Fig. 2(c) shows the calculated $T_{N,min}$ as a function of T_0 in the limit of perfect thermalization $T_{\rm S} = T_{\rm ph} = T_0$. The red (light) and blue (dark) solid lines are the results of Eqs. (1) and (2) for equilibrium phonons in the island, $T_{\rm ph} = T_0$. The red (light) line is obtained with r = 0, so that the S electrode overheats at most all the way to the large-area bonding pad. Especially toward the lowest bath temperatures, the observed cooling in zero field is considerably weaker than the prediction of the model for perfect thermalization of S electrodes. To estimate the effect in the optimum field, we set r = 1 in the 10- μ m-wide electrode section, but keep r = 0 in the narrower section. The result is shown as the solid blue (dark) line in Fig. 2(c). In our samples, a considerable fraction of the N island is located on top of the S electrodes such that $T_{\rm ph}$ can be essentially higher than T_0 . As a worst-case estimate, we assume the N island phonons to be overheated to $T_{\rm ph} = T_{\rm S}$. The results for the above two cases of full and partial S electrode overheating are shown as the red (light) and blue (dark) dashed-dotted lines, respectively. The predicted influence of the field is now stronger, and the measured cooling in both the zero and optimum field is bracketed between the solid and the dashed-dotted line. Approximate phonon temperatures $T_{\rm ph}$ at $V_{\rm opt}$ that reproduce exactly the



FIG. 3. (Color online) Cooling curves in selected magnetic fields for parallel SINIS coolers with different S electrode geometries, at fixed $T_0 \simeq 130$ mK. (a) When initially wide S leads are followed by a narrower section, applying a finite B_{\perp} weakens the cooling monotonously. (b) In a structure with initially narrow leads, the behavior is nonmonotonic, with enhanced cooling in small fields. The insets sketch one half of the cooler structure with ten NIS junctions in parallel.

observed $T_{\rm N,min}$ are displayed in Fig. 2(e). In both zero field (red/light, upper curve) and in the optimum field (lower curve), $T_{\rm ph}$ reflects the temperature $T_{\rm S}$ of the QPs close to the junction, ranging from close to $0.8T_{\rm S}$ at $T_0 = 0.1$ K to $\sim 0.95T_{\rm S}$ at $T_0 = 0.5$ K. We stress that the large field-induced improvement evident in Figs. 1 and 2 is observed because of considerable S electrode overheating in zero field. It causes also the significant increase in $V_{\rm opt}$ as B_{\perp} is increased from zero: $V_{\rm opt}$ is close to the ideal value¹⁴ $2(\Delta - 0.66k_{\rm B}T_{\rm N})/e$ only at optimum B_{\perp} .

Conclusions. To emphasize the role of the S electrode geometry, we performed additional experiments on parallel SINIS coolers. As shown in Fig. 3(a), in a sample with initially wide leads, vortices first form close to the junctions, and applying B_{\perp} monotonously weakens the cooling. In contrast, with narrow leads close to the junctions as in Fig. 3(b), the cooling is optimized at a finite B_{\perp} .

In conclusion, we observed that a small magnetic field enhances relaxation processes in a superconductor, thus stabilizing superconductivity in nonequilibrium conditions. Significantly improved electronic cooling in a tunnel junction

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was achieved in a small perpendicular magnetic field. The enhancement of relaxation can be relevant also for "reentrant superconductivity" observed in Zn nanowires^{10,11} driven out of equilibrium by supercritical current. A quasiequilibrium model accounts for the field-improved QP relaxation in the S leads. The work can provide means for optimizing the performance of superconducting nanostructures, and sheds additional light on the unsolved problem of nonequilibrium and residual quasiparticles.

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